

Vishay Siliconix

P-Channel 2.5 V (G-S) MOSFET

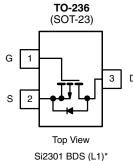
PRODUCT	PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A) ^b			
- 20	0.100 at V _{GS} = - 4.5 V	- 2.4			
- 20	0.150 at V _{GS} = - 2.5 V	- 2.0			

FEATURES

- Halogen-free According to IEC 61249-2-21
- TrenchFET® Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC



HALOGEN FREE



* Marking Code

Ordering Information: Si2301BDS-T1-E3 (Lead (Pb)-free)

Si2301BDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T	_A = 25 °C, unle	ess otherwise	noted)			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Brain Comment /T 450 °C)b	T _A = 25 °C	I-	- 2.4	- 2.2		
Continuous Drain Current (T _J = 150 °C) ^b	T _A = 70 °C	- I _D	- 1.9	- 1.8		
Pulsed Drain Current ^a		I _{DM}	- 10		Α	
Continuous Source Current (Diode Conduction) ^b		I _S	- 0.72	- 0.6		
D D: : :: h	T _A = 25 °C	P _D	0.9	0.7	W	
Power Dissipation ^b	T _A = 70 °C	1 'D	0.57	0.45	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^b	- R _{thJA}	120	145	°C/W	
Maximum Junction-to-Ambient ^c	' 'thJA	140	175	C/VV	

- a. Pulse width limited by maximum junction temperature.
- b. Surface mounted on FR4 board, $t \le 5$ s.
- c. Surface mounted on FR4 board.

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

Si2301BDS

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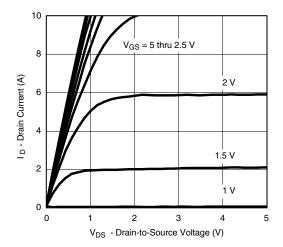
SPECIFICATIONS (T _J = 25	°C, unless	otherwise noted)				
				Limits		
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 0.45		- 0.95	v
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA
Zarra Cata Valtana Brain Commant		V _{DS} = - 20 V, V _{GS} = 0 V			- 1	
Zero Gate Voltage Drain Current	IDSS	V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 55 °C			- 10	μΑ
		$V_{DS} \le -5 V$, $V_{GS} = -4.5 V$	- 6			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -2.5 \text{ V}$	- 3			Α
		$V_{GS} = -4.5 \text{ V}, I_D = -2.8 \text{ A}$		0.080	0.100	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 2 A		0.110	0.150	Ω
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_{D} = -2.8 \text{ A}$		6.5		S
Diode Forward Voltage	V_{SD}	$I_S = -0.75 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.80	- 1.2	V
Dynamic ^b				•		
Total Gate Charge	Qg	V CVV 45V		4.5	10	
Gate-Source Charge	Q _{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}$ $I_{D} \cong -2.8 \text{ A}$		0.7		nC
Gate-Drain Charge	Q_{gd}	ID = -2.0 A		1.1		
Gate Resistance	R_g	f = 1 MHz	2	8	16	Ω
Input Capacitance	C _{iss}			375		
Output Capacitance	C _{oss}	$V_{DS} = -6 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		95		pF
Reverse Transfer Capacitance	C _{rss}			65		
Switching ^c						
Turn On Time	t _{d(on)}			20	30	
Turn-On Time	t _r	$V_{DD} = -6 \text{ V}, R_L = 6 \Omega$ $I_D \cong -1 \text{ A}, V_{GEN} = -4.5 \text{ V}$		40	60	
Turn-Off Time	t _{d(off)}	$R_a = 6 \Omega$		30	45	ns
rum-On time	t _f	g		20	30]

- a. Pulse test: pulse width \leq 300 μ s duty cycle \leq 2 %.
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

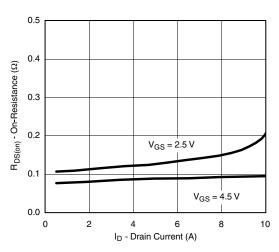
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



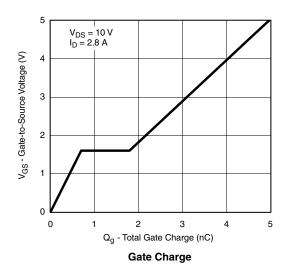
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

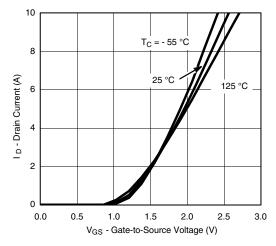


Output Characteristics

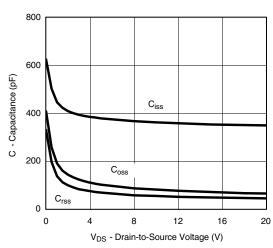


On-Resistance vs. Drain Current

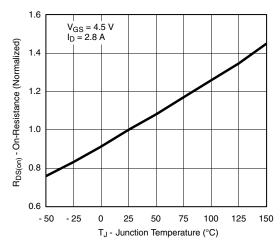




Transfer Characteristics



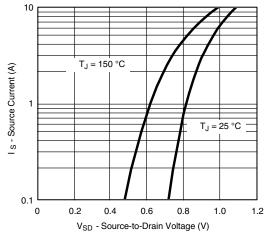
Capacitance



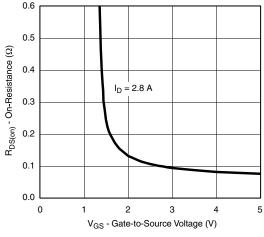
On-Resistance vs. Junction Temperature

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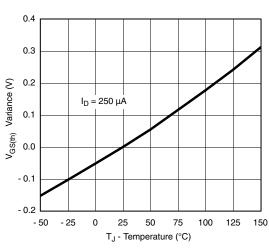
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



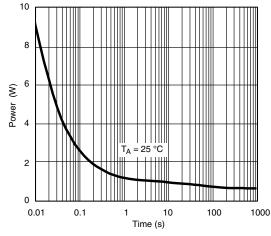
Source-Drain Diode Forward Voltage



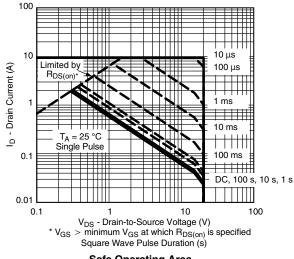
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



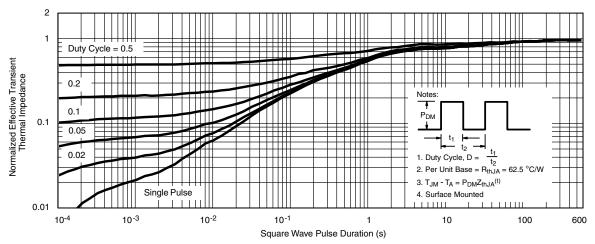
Single Pulse Power



Safe Operating Area

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

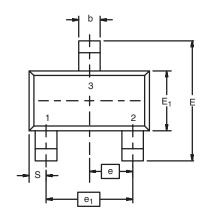


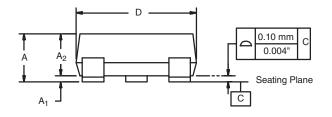
Normalized Thermal Transient Impedance, Junction-to-Ambient

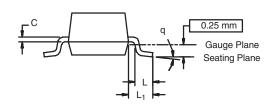
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SOT-23 (TO-236): 3-LEAD







Dim	MILLIMETERS		INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	

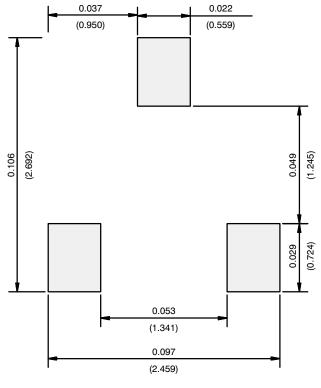
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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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